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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yeo, *et al.* Docket No.: TSM03-0511  
Serial No.: 10/669,395 Art Unit: 2811  
Filed: September 24, 2003 Examiner: Gebremariam, Samuel A.  
For: Multiple-Gate Transistors Formed on Bulk Substrates


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Date of Deposit: December 1, 2004

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Certificate of Mailing via First Class Mail (1 page)  
Amendment (13 pages)  
One (1) Sheet Replacement Drawings  
Return Postcard

Respectfully submitted,

  
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Mail Stop: Amendment  
Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

The following amendments and remarks are presented in response to the Examiner's Office Action mailed September 9, 2004. Please amend the above-referenced application as follows.